



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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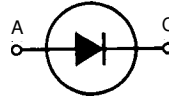
Super Fast Recovery Diode

DSDI 60

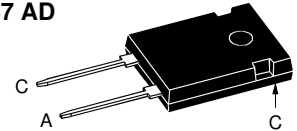
$I_{FAVM} = 63 \text{ A}$
 $V_{RRM} = 1400-1800 \text{ V}$
 $t_{rr} = 40 \text{ ns}$

Preliminary Data

V_{RSM}	V_{RRM}	Type
V	V	
1400	1400	DSDI 60-14A
1600	1600	DSDI 60-16A
1800	1800	DSDI 60-18A



TO-247 AD



A = Anode, C = Cathode

Symbol	Test Conditions	Maximum Ratings	
I_{FRMS}	$T_{VJ} = T_{VJM}$	100	A
I_{FAVM} ①	$T_C = 60^\circ\text{C}$; rectangular, $d = 0.5$	63	A
I_{FRM}	$t_p < 10 \mu\text{s}$; rep. rating, pulse width limited by T_{VJM}	800	A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine	500	A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	540	A
	$T_{VJ} = 150^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine	450	A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	480	A
I^2t	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine	1250	A^2s
	$t = 8.3 \text{ ms}$ (60 Hz), sine	1200	A^2s
	$T_{VJ} = 150^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine	1000	A^2s
	$t = 8.3 \text{ ms}$ (60 Hz), sine	950	A^2s
T_{VJ}		-40...+150	$^\circ\text{C}$
T_{VJM}		150	$^\circ\text{C}$
T_{stg}		-40...+150	$^\circ\text{C}$
P_{tot}	$T_C = 25^\circ\text{C}$	416	W
M_d	Mounting torque	0.8...1.2	Nm
Weight		6	g

Features

- International standard package JEDEC TO-247 AD
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low I_{RM} -values
- Soft recovery behaviour
- Epoxy meets UL 94V-0
- Creepage distance between leads 8.5 mm

Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

Dimensions

See DSEI 60-12 on page D5 - 27

Symbol	Test Conditions	Characteristic Values			
		typ.	max.		
I_R	$T_{VJ} = 25^\circ\text{C}$	$V_R = V_{RRM}$	1	2	mA
	$T_{VJ} = 25^\circ\text{C}$	$V_R = 0.8 \cdot V_{RRM}$	0.5		mA
	$T_{VJ} = 125^\circ\text{C}$	$V_R = 0.8 \cdot V_{RRM}$	3		mA
V_F	$I_F = 70 \text{ A}$; $T_{VJ} = 125^\circ\text{C}$		2.6		V
	$T_{VJ} = 25^\circ\text{C}$			4.1	V
V_{T0}	For power-loss calculations only			1.9	V
r_T	$T_{VJ} = T_{VJM}$			10	$\text{m}\Omega$
R_{thJC}				0.4	K/W
R_{thCK}			0.25		K/W
t_{rr}	$I_F = 1 \text{ A}$; $-di/dt = 200 \text{ A}/\mu\text{s}$; $V_R = 30 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$		40		ns
t_{rr}	$I_F = 70 \text{ A}$; $-di/dt = 500 \text{ A}/\mu\text{s}$; $V_R = 1000 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$		300		ns
		I_{RM}	60		A
t_{rr}	$I_F = 70 \text{ A}$; $-di/dt = 500 \text{ A}/\mu\text{s}$; $V_R = 1000 \text{ V}$; $T_{VJ} = 125^\circ\text{C}$		400		ns
		I_{RM}	85		A

① I_{FAVM} rating includes reverse blocking losses at T_{VJM} , $V_R = 0.8 V_{RRM}$, duty cycle $d = 0.5$
 Data according to IEC 60747
 IXYS reserves the right to change limits, test conditions and dimensions